

Teflon woven glass fabric with ceramic filler copper-clad laminates

BTM-1/2

BTM-1/2 is laminated by laying up of the imported varnished glass cloth with Teflon resin and filled with Nano-ceramic, with scientific formulation and strict manufacturing process. This product has improved heat dissipation and smaller thermal expansion coefficient compared to BM series products.

Technical Specifications:

Appearance	Meet the specification requirements for the laminate of microwave PCB by National and Military Standards.					
Types	BTM-1/2 (255)	BTM-1/2 (265)	BTM-1/2 (285)	BTM-1/2 (294)	BTM-1/2 (300)	BTM-1/2 (320)
	BTM-1/2 (338)	BTM-1/2 (350)	BTM-1/2 (400)	BTM-1/2 (440)	BTM-1/2 (615)	BTM-1/2 (1020)
Dimension (mm)	610×460	600×500	1220×914	1220×1000	1500×1000	
	For special dimension, customized laminates is available.					
Thickness and Tolerance (mm)	Laminate thickness	0.254	0.508	0.762	0.787	1.016
	Tolerance	±0.025	±0.05	±0.05	±0.05	±0.05
	Laminate thickness	1.27	1.524	2.0	3.0	4.0
	Tolerance	±0.05	±0.05	±0.075	±0.09	±0.1
	Laminate thickness	5.0	6.0	9.0	10.0	12.0
	Tolerance	±0.1	±0.12	±0.18	±0.18	±0.2
Mechanical Strength	Cutting/punching Strength	Thickness<1mm, no burrs after cutting, minimum space between two punching holes is 0.55mm, no delamination.				
		Thickness≥1mm, no burrs after cutting, minimum space between two punching holes is 1.10mm, no delamination.				
	Peel strength (1oz copper)	Normal state: ≥18N/cm; No bubble、delamination、peel strength≥15N/cm (in the constant humidity and temperature、and keep in the melting solder of 265°C±2°C for 20 seconds) .				
Thermal stress	After solder float, 260° C, 10s, ≥3 times , no delamination and blister.					
Chemical Property	According to the properties of laminate, the chemical etching method for PCB can be used. The dielectric properties of laminate are not changed. The plating through hole can be done, but the sodium treatment or the plasma treatment must be used.					
Electrical Property	Name	Test condition		Unit		Value
	Density	Normal state		g/ cm ³		2.1~3.0
	Moisture	Dip in the distilled water of		%		≤0.05

Absorption	20±2℃ for 24 hours			
Operating Temperature	High-low temperature chamber		℃	-50℃~+260℃
Thermal Conductivity			W/m/k	0.6~0.9
CTE (typical)	-55~288℃ (ε _r : 2.55~3.0)	ppm/℃	15 (x)	
			15 (y)	
			65 (z)	
CTE (typical)	-55~288℃ (ε _r : 3.2~3.5)	ppm/℃	15 (x)	
			15 (y)	
			55 (z)	
CTE (typical)	-55~288℃ (ε _r : 4.0~10.2)	ppm/℃	12 (x)	
			14 (y)	
			50 (z)	
Shrinkage Factor	2 hours in boiling water		%	< 0.0002
Surface Resistivity	500V DC	Normal state	M • Ω	≥ 1 × 10 ⁶
		Constant humidity and temperature		≥ 1 × 10 ⁵
Volume Resistivity	Normal state		MΩ.cm	≥ 1 × 10 ⁷
	Constant humidity and temperature			≥ 1 × 10 ⁶
Surface dielectric strength	Normal state		δ=1mm (Kv/mm)	≥ 1.2
	Constant humidity and temperature			≥ 1.1
Dielectric Constant	10GHz		ε _r	2.85±0.05、2.94±0.05 3.00±0.05、3.20±0.05 3.38±0.05、3.50±0.05 4.00±0.08、4.40±0.1 6.15±0.15、10.2±0.25
Thermal Coefficient of ε _r (PPM/℃) -50~150℃	ε _r		Value	
	2.85, 2.94		-85	
	3.0, 3.2		-75	
	3.38		-65	
	3.5		-60	
	4.0		-60	
	4.4		-60	
	6.15		-55	
Dissipation Factor	10GHz	tg δ	2.55~3.0	≤ 1.5 × 10 ⁻³
		tg δ	3.0~3.5	≤ 2.0 × 10 ⁻³
		tg δ	4.0~10.20	≤ 2.5 × 10 ⁻³
UL Flammability	94 V-0			